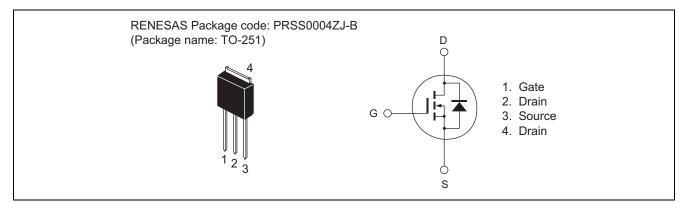


600V - 2A - MOS FET High Speed Power Switching Datasheet

Features

- Low on-resistance RDS(on) = 5.7 Ω typ. (at I_D = 1 A, V_{GS} = 10 V, Ta = 25°C)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	600	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	2	А
Drain peak current	I _{D (pulse)} Note1	4	А
Body-drain diode reverse drain current	I _{DR}	2	А
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	4	А
Avalanche current	I _{AP} ^{Note3}	1	А
Avalanche energy	E _{AR} ^{Note3}	0.05	mJ
Channel dissipation	Pch ^{Note2}	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle$ \leq 1%

2. Value at Tc = 25° C

3. STch = 25°C, Tch \leq 150°C



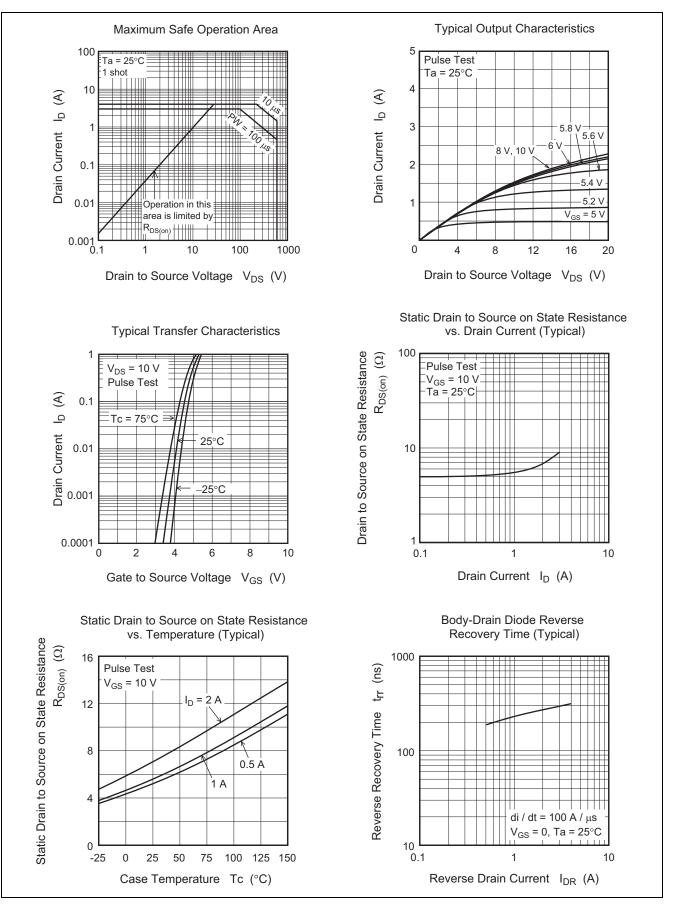
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	600	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μΑ	$V_{DS} = 600 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}		5.7	6.8	Ω	$I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						
Input capacitance	Ciss	_	165	—	pF	V _{DS} = 25 V
Output capacitance	Coss	—	20	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	2.5	_	pF	
Turn-on delay time	t _{d(on)}	_	28	—	ns	I _D = 1 A
Rise time	tr	_	17	—	ns	$V_{GS} = 10 V$ $R_L = 300 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	47	—	ns	
Fall time	t _f	_	20	—	ns	
Total gate charge	Qg	_	6.2	—	nC	V _{DD} = 480 V
Gate to source charge	Qgs	_	1.1	—	nC	V _{GS} = 10 V I _D = 2 A
Gate to drain charge	Qgd	_	3.6	—	nC	
Body-drain diode forward voltage	V _{DF}	—	0.87	1.45	V	$I_F = 2 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	—	260	—	ns	$I_F = 2 A, V_{GS} = 0$
						di _F /dt = 100 A/µs

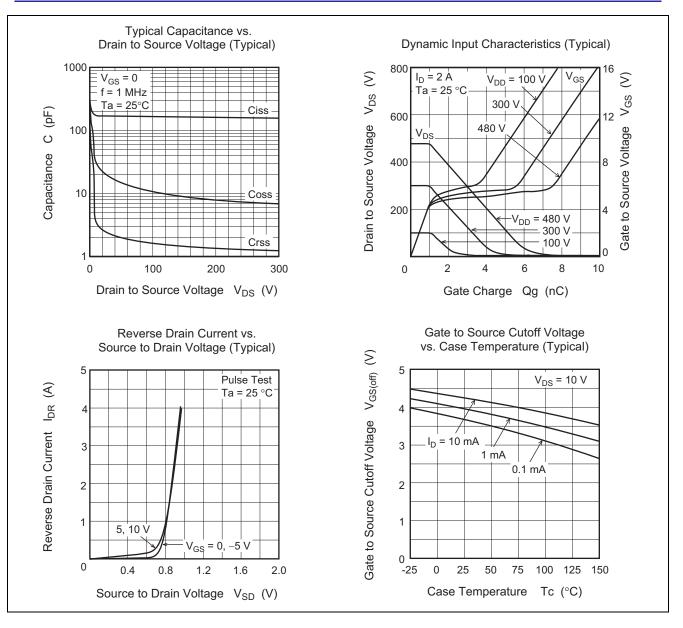
Notes: 4. Pulse test



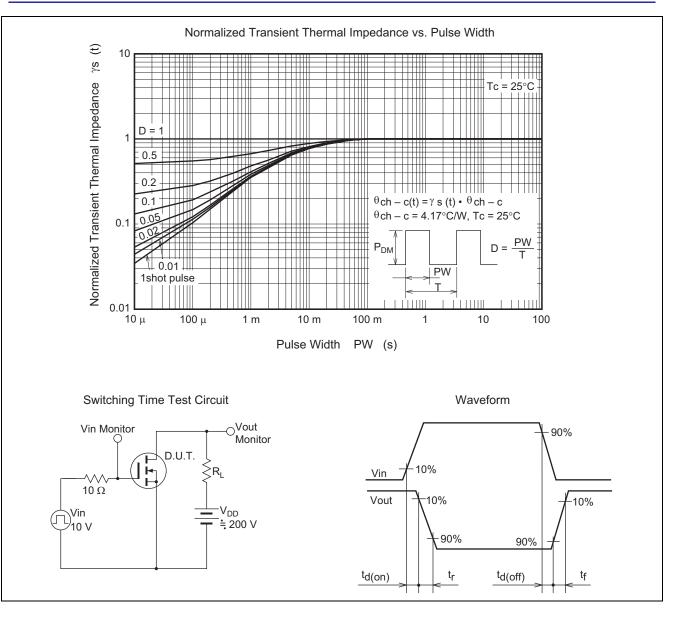
Main Characteristics





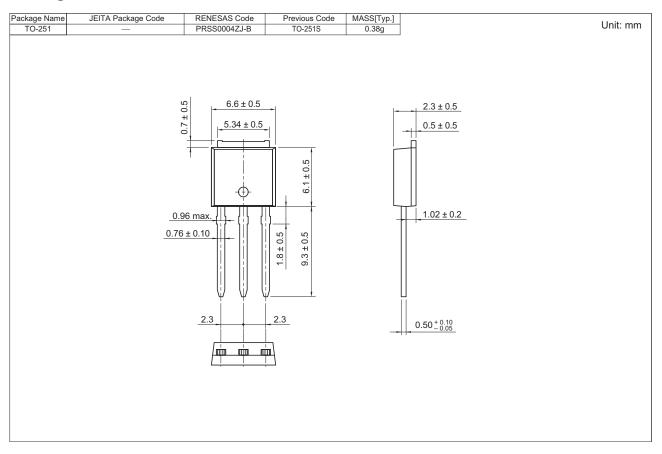








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK6002DPH-E0#T2	70 pcs	Tube



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Renesas Electronics Corporation

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Renesas Electronics America Inc. 2880 Scott Bouldsand Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1011 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH Arcadiastrasse 10, 40472 Disseldorf, Germany Tel: +49-211-65030, Fax: +44-11650-31327

Renesas Electronics China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China Tel: +480-214-8255-1155, Fax: +480-210-8235-7679

Renesas Electronics (Shanghal) Co., Ltd. 10th 1204, 205, AZIA Center, No.1233 Luijazui Fling Rd., Pudong District, Shanghai 200120, China Tel: +860-2457-1518, Fax: +862-2467-7898

Renesas Electronics Hong Kong Limited Unit 1204, 205, AZIA Center, No. 1233 Luijazui Fling Rd., Pudong District, Shanghai 200120, China Tel: +860-2457-5187, Fax: +862-2467-7896

Renesas Electronics Taiwan Co., Ltd. 10th 1501-1613, 10F, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2866-9318, Fax: +852-2866-9022/9044

Renesas Electronics Taiwan Co., Ltd. 10t, No.363, Fu Shing North Road, Taipei, Taiwan Tel: +862-24175-9600, Fax: +862-24175-9670

Renesas Electronics Taiwan Co., Ltd. 10t, No.363, Fu Shing North Road, Centure Place, 193 Prince Edward Boad West, Mongkok, Kowloon, Hong Kong Tel: +60-37755-9390, Fax: +862-24175-9670

Renesas Electronics Taiwan Co., Ltd. 10th 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Pe